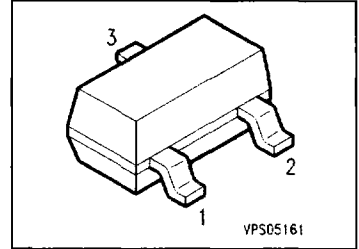


### Features

- For AF input stages and driver applications
- High current gain
- Low collector-emitter saturation voltage
- Low noise between 30 Hz and 15 kHz
- Complementary types: BC 856, BC 857, BC 859, BC 860 (PNP)



Type	Marking	Ordering Code (tape and reel)	Pin Configuration			Package <sup>1)</sup>
			1	2	3	
BC 846 A	1As	Q62702-C1772	B	E	C	SOT-23
BC 846 B	1Bs	Q62702-C1746				
BC 847 A	1Es	Q62702-C1884				
BC 847 B	1Fs	Q62702-C1687				
BC 847 C	1Gs	Q62702-C1715				
BC 848 A	1Js	Q62702-C1741				
BC 848 B	1Ks	Q62702-C1704				
BC 848 C	1Ls	Q62702-C1506				
BC 849 B	2Bs	Q62702-C1727				
BC 849 C	2Cs	Q62702-C1713				
BC 850 B	2Fs	Q62702-C1885				
BC 850 C	2Gs	Q62702-C1712				

<sup>1)</sup>For detailed information see chapter Package Outlines.

**Maximum Ratings**

Parameter	Symbol	Values			Unit
		BC 846	BC 847 BC 850	BC 848 BC 849	
Collector-emitter voltage	$V_{CE0}$	65	45	30	V
Collector-base voltage	$V_{CB0}$	80	50	30	
Collector-emitter voltage	$V_{CES}$	80	50	30	
Emitter-base voltage	$V_{EB0}$	6	6	5	
Collector current	$I_C$	100			mA
Peak collector current	$I_{CM}$	200			
Peak base current	$I_{BM}$	200			
Peak emitter current	$I_{EM}$	200			
Total power dissipation, $T_s = 71\text{ °C}$	$P_{tot}$	330			mW
Junction temperature	$T_j$	150			°C
Storage temperature range	$T_{stg}$	- 65 ... + 150			

**Thermal Resistance**

Junction - ambient <sup>1)</sup>	$R_{thJA}$	≤ 310	K/W
Junction - soldering point	$R_{thJS}$	≤ 240	

<sup>1)</sup>Package mounted on epoxy pcb 40 mm × 40 mm × 1.5 mm/6 cm<sup>2</sup> Cu.

## Electrical Characteristics

at  $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise specified.

Parameter	Symbol	Values			Unit		
		min.	typ.	max.			
<b>DC characteristics</b>							
Collector-emitter breakdown voltage $I_C = 10\text{ mA}$	$V_{(BR)CEO}$	BC 846	65	—	—	V	
BC 847, BC 850		45	—	—			
BC 848, BC 849		30	—	—			
Collector-base breakdown voltage $I_C = 10\text{ }\mu\text{A}$	$V_{(BR)CBO}$	BC 846	80	—	—		
BC 847, BC 850		50	—	—			
BC 848, BC 849		30	—	—			
Collector-emitter breakdown voltage $I_C = 10\text{ }\mu\text{A}$ , $V_{BE} = 0$	$V_{(BR)CES}$	BC 846	80	—	—		
BC 847, BC 850		50	—	—			
BC 848, BC 849		30	—	—			
Emitter-base breakdown voltage $I_E = 1\text{ }\mu\text{A}$	$V_{(BR)EBO}$	BC 846, BC 847	6	—	—		
BC 848, BC 849, BC 850		5	—	—			
Collector cutoff current $V_{CB} = 30\text{ V}$ $V_{CB} = 30\text{ V}$ , $T_A = 150\text{ }^\circ\text{C}$	$I_{CBO}$		—	—	15	nA	
				—	—	5	$\mu\text{A}$
DC current gain $I_C = 10\text{ }\mu\text{A}$ , $V_{CE} = 5\text{ V}$ BC 846 A, BC 847 A, BC 848 A BC 846 B ... BC 850 B BC 847 C, BC 848 C, BC 849 C, BC 850 C $I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$ BC 846 A, BC 847 A, BC 848 A BC 846 B ... BC 850 B BC 847 C, BC 848 C, BC 849 C, BC 850 C	$h_{FE}$		—	140	—	—	
				—	250		—
				—	480		—
				110	180		220
				200	290		450
				420	520		800
Collector-emitter saturation voltage <sup>1)</sup> $I_C = 10\text{ mA}$ , $I_B = 0.5\text{ mA}$ $I_C = 100\text{ mA}$ , $I_B = 5\text{ mA}$	$V_{CEsat}$		—	90	250	mV	
				—	200		600
Base-emitter saturation voltage <sup>1)</sup> $I_C = 10\text{ mA}$ , $I_B = 0.5\text{ mA}$ $I_C = 100\text{ mA}$ , $I_B = 5\text{ mA}$	$V_{BEsat}$		—	700	—		
				—	900		—
Base-emitter voltage $I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$ $I_C = 10\text{ mA}$ , $V_{CE} = 5\text{ V}$	$V_{BE(on)}$		580	660	700		
				—	—		770

<sup>1)</sup>Pulse test:  $t_s \leq 300\text{ }\mu\text{s}$ ,  $D = 2\text{ }%$ .

**Electrical Characteristics**

at  $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise specified.

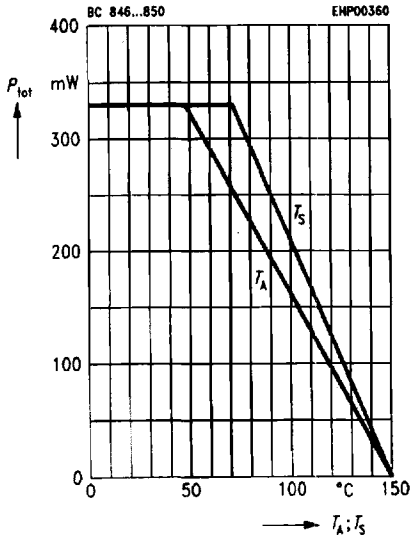
Parameter	Symbol	Values			Unit
		min.	typ.	max.	

**AC characteristics**

Transition frequency $I_C = 20\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $f = 100\text{ MHz}$	$f_T$	–	250	–	MHz
Output capacitance $V_{CB} = 10\text{ V}$ , $f = 1\text{ MHz}$	$C_{ob0}$	–	3	–	pF
Input capacitance $V_{CB} = 0.5\text{ V}$ , $f = 1\text{ MHz}$	$C_{ib0}$	–	8	–	
Short-circuit input impedance $I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $f = 1\text{ kHz}$ BC 846 A ... BC 848 A BC 846 B ... BC 850 B BC 847 C ... BC 850 C	$h_{11e}$	– – –	– 2.7 4.5 8.7	– – –	k $\Omega$
Open-circuit reverse voltage transfer ratio $I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $f = 1\text{ kHz}$ BC 846 A ... BC 848 A BC 846 B ... BC 850 B BC 847 C ... BC 850 C	$h_{12e}$	– – –	– 1.5 2.0 3.0	– – –	$10^{-4}$
Short-circuit forward current transfer ratio $I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $f = 1\text{ kHz}$ BC 846 A ... BC 848 A BC 846 B ... BC 850 B BC 847 C ... BC 850 C	$h_{21e}$	– – –	– 200 330 600	– – –	–
Open-circuit output admittance $I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $f = 1\text{ kHz}$ BC 846 A ... BC 848 A BC 846 B ... BC 850 B BC 847 C ... BC 850 C	$h_{22e}$	– – –	– 18 30 60	– – –	$\mu\text{S}$
Noise figure $I_C = 0.2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $R_S = 2\text{ k}\Omega$ $f = 30\text{ Hz} \dots 15\text{ kHz}$ BC 849 BC 850 $f = 1\text{ kHz}$ , $\Delta f = 200\text{ Hz}$ BC 849 BC 850	$F$	– – – –	– 1.4 1.4 1.2 1.0	4 3 4 4	dB
Equivalent noise voltage $I_C = 0.2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $R_S = 2\text{ k}\Omega$ $f = 10\text{ Hz} \dots 50\text{ Hz}$ BC 850	$V_n$	–	–	0.135	$\mu\text{V}$

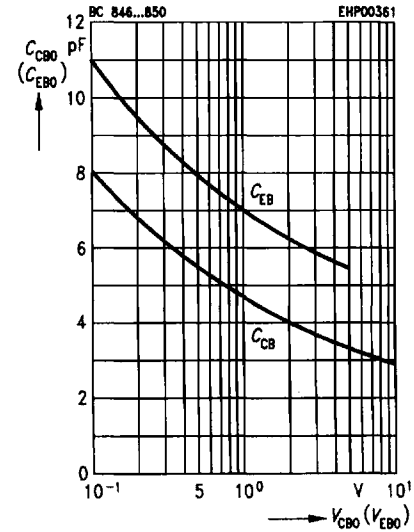
**Total power dissipation  $P_{tot} = f(T_A^*; T_S)$**

\* Package mounted on epoxy

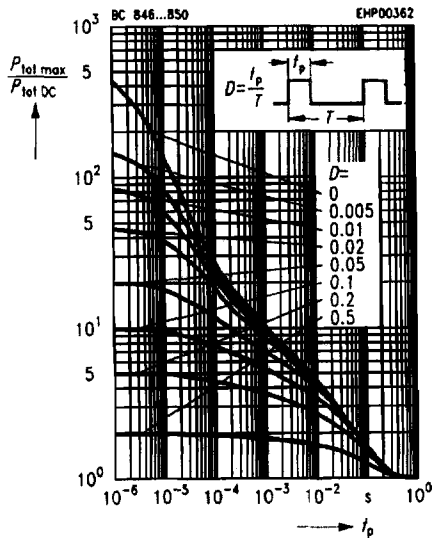


**Collector-base capacitance  $C_{CB0} = f(V_{CB0})$**

**Emitter-base capacitance  $C_{EB0} = f(V_{EB0})$**

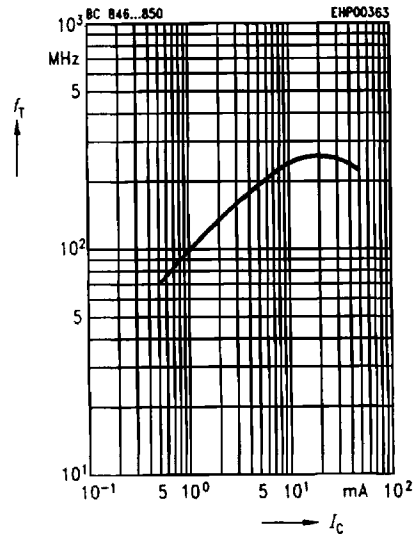


**Permissible pulse load  $P_{tot max}/P_{tot DC} = f(t_p)$**

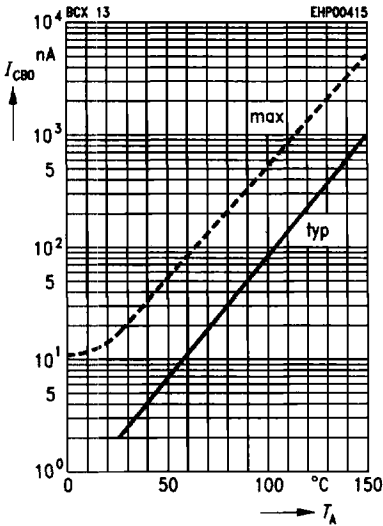


**Transition frequency  $f_T = f(I_C)$**

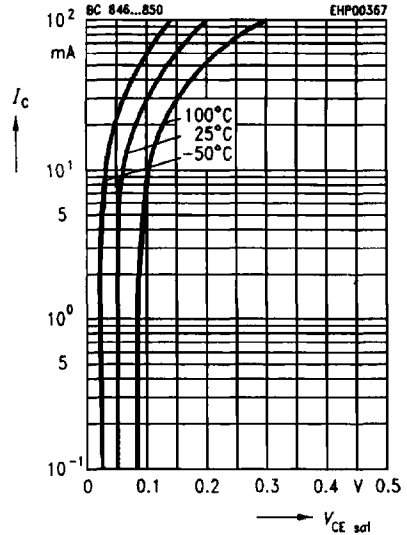
$V_{CE} = 5 V$



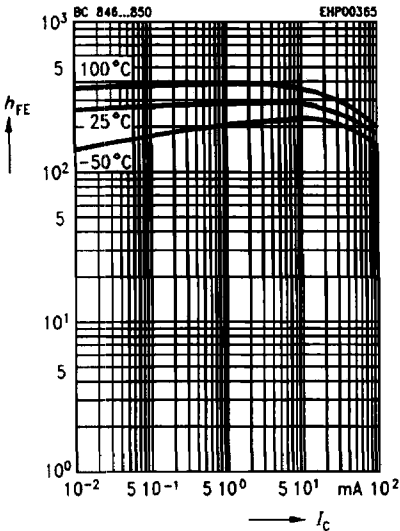
**Collector cutoff current  $I_{CBO} = f(T_A)$**   
 $V_{CB} = 30\text{ V}$



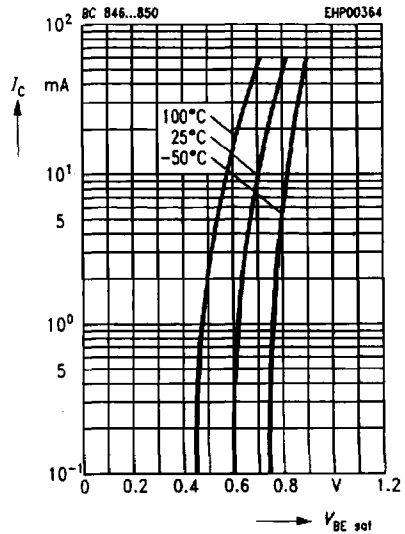
**Collector-emitter saturation voltage**  
 $I_C = f(V_{CEsat}), h_{FE} = 20$



**DC current gain  $h_{FE} = f(I_C)$**   
 $V_{CE} = 5\text{ V}$

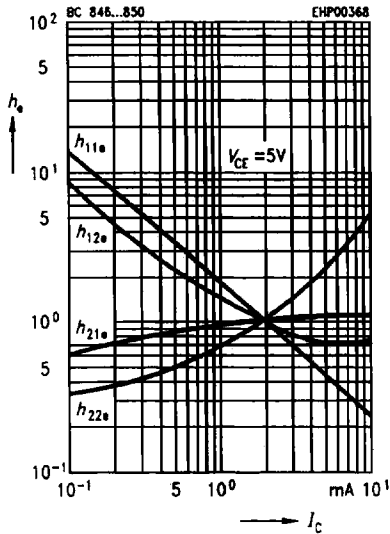


**Base-emitter saturation voltage**  
 $I_C = f(V_{BEsat}), h_{FE} = 20$



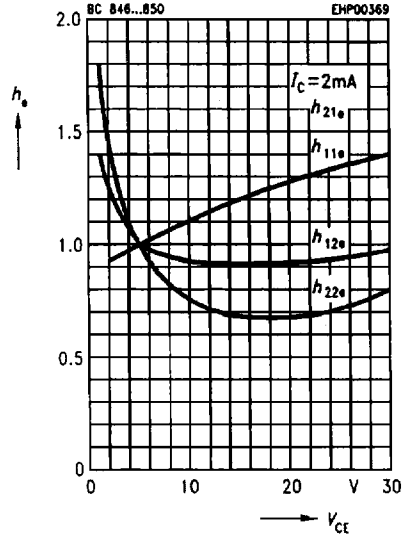
**h parameter  $h_o = f(I_C)$  normalized**

$V_{CE} = 5\text{ V}$



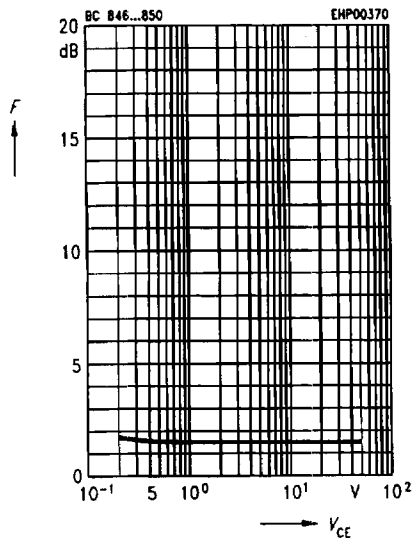
**h parameter  $h_o = f(V_{CE})$  normalized**

$I_C = 2\text{ mA}$



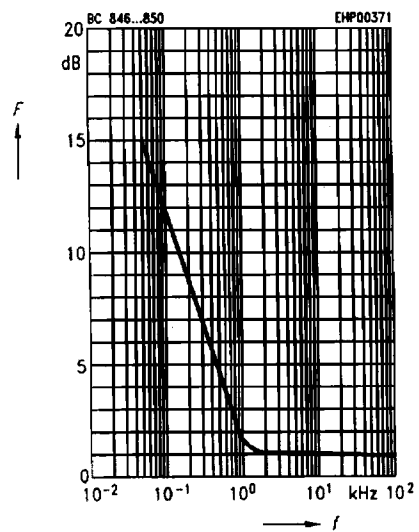
**Noise figure  $F = f(V_{CE})$**

$I_C = 0.2\text{ mA}$ ,  $R_s = 2\text{ k}\Omega$ ,  $f = 1\text{ kHz}$



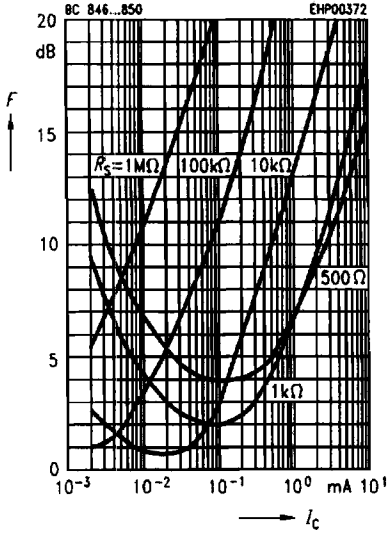
**Noise figure  $F = f(f)$**

$I_C = 0.2\text{ mA}$ ,  $V_{CE} = 5\text{ V}$ ,  $R_s = 2\text{ k}\Omega$



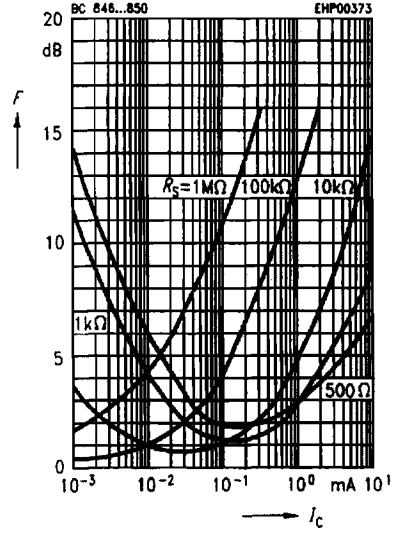
**Noise figure  $F = f(I_C)$**

$V_{CE} = 5\text{ V}, f = 120\text{ Hz}$



**Noise figure  $F = f(I_C)$**

$V_{CE} = 5\text{ V}, f = 1\text{ kHz}$



**Noise figure  $F = f(I_C)$**

$V_{CE} = 5\text{ V}, f = 10\text{ kHz}$

